

# General purpose transistor (dual transistors)

## IMX17

### ●Features

- 1) Two 2SD1484K chips in an SMT package.
- 2) Mounting possible with SMT3 automatic mounting machine.
- 3) Transistor elements are independent, eliminating interference.
- 4) High collector current.  
 $I_c = 500\text{mA}$
- 5) Mounting cost and area can be cut in half.

### ●Structure

Epitaxial planar type  
NPN silicon transistor

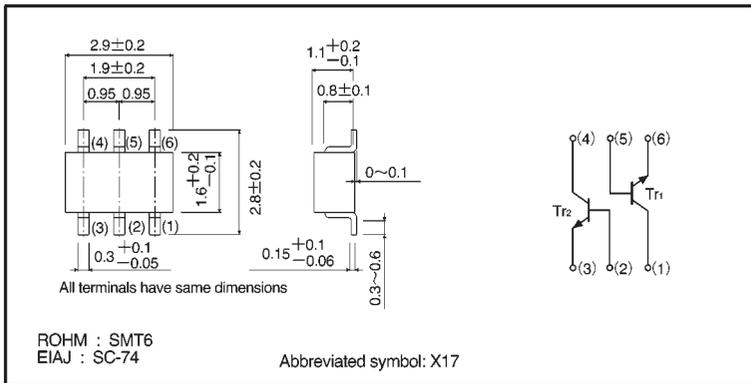
The following characteristics apply to both  $Tr_1$  and  $Tr_2$ .

### ●Absolute maximum ratings ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Limits	Unit
Collector-base voltage	$V_{CBO}$	60	V
Collector-emitter voltage	$V_{CEO}$	50	V
Emitter-base voltage	$V_{EBO}$	5	V
Collector current	$I_c$	500	mA
Power dissipation	$P_d$	300 (TOTAL)	mW *
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	$-55 \sim +150$	$^\circ\text{C}$

\*200 mW per element must not be exceeded.

### ●External dimensions (Units: mm)



●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	$BV_{CBO}$	60	—	—	V	$I_C=100\ \mu A$
Collector-emitter breakdown voltage	$BV_{CEO}$	50	—	—	V	$I_C=1mA$
Emitter-base breakdown voltage	$BV_{EBO}$	5	—	—	V	$I_E=100\ \mu A$
Collector cutoff current	$I_{CBO}$	—	—	0.1	$\mu A$	$V_{CB}=30V$
Emitter cutoff current	$I_{EBO}$	—	—	0.1	$\mu A$	$V_{EB}=4V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	—	0.6	V	$I_C/I_B=500mA/50mA$
DC current transfer ratio	$h_{FE}$	120	—	390	—	$V_{CE}=3V, I_C=100mA$ *
Transition frequency	$f_T$	—	250	—	MHz	$V_{CE}=5V, I_E=-20mA, f=100MHz$
Output capacitance	$C_{ob}$	—	7	—	pF	$V_{CB}=10V, I_E=0A, f=1MHz$

\* Measured using pulse current.

●Packaging specifications

Part No.	Packaging type	Taping
	Code	T110
	Basic ordering unit (pieces)	3000
IMX17		

●Electrical characteristic curves

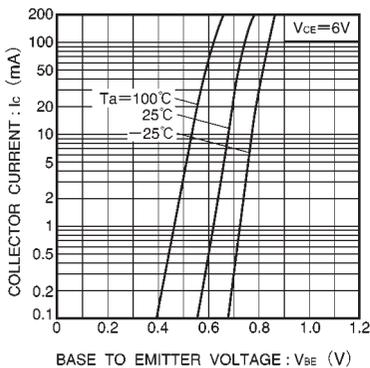


Fig.1 Grounded emitter propagation characteristics

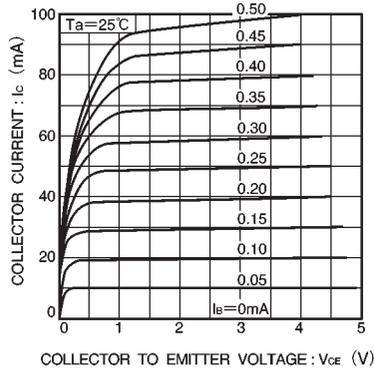


Fig.2 Grounded emitter output characteristics

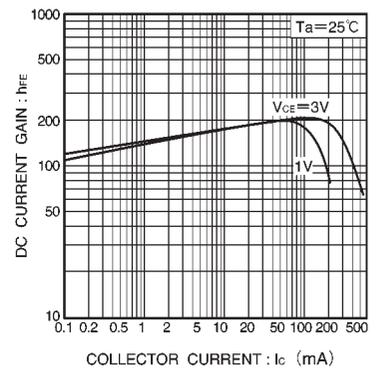


Fig.3 DC current gain vs. collector current (I)

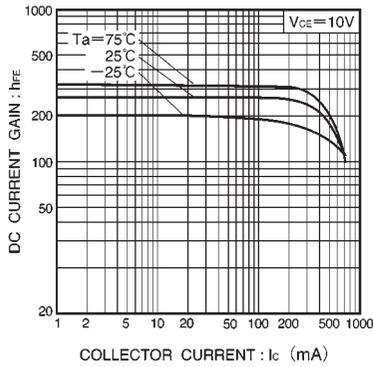


Fig.4 DC current gain vs. collector current ( II )

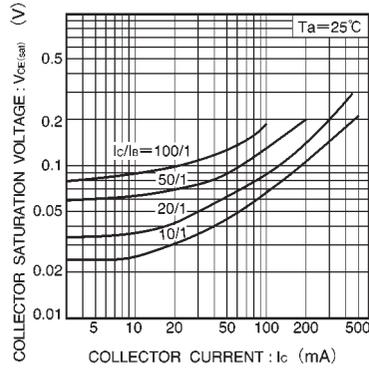


Fig.5 Collector-emitter saturation voltage vs. collector current

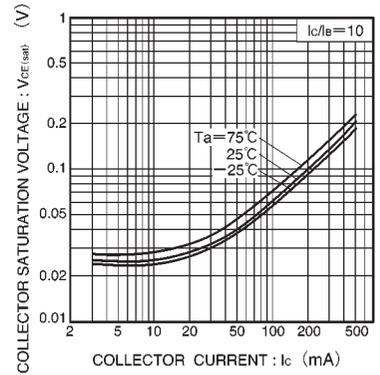


Fig.6 Collector-emitter saturation voltage vs. collector current

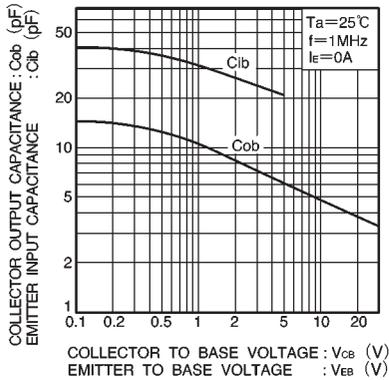


Fig.7 Input/output capacitance vs. voltage

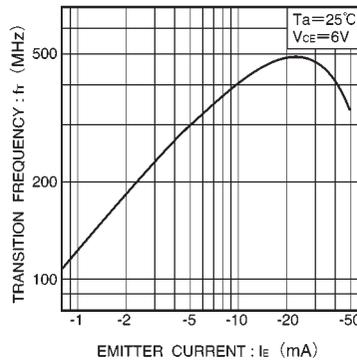


Fig.8 Gain bandwidth product vs. emitter current

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